

BM9166

250mA CMOS LDO

GENERAL DESCRIPTION

The BM9166 family is a positive voltage linear regulator developed utilizing CMOS technology featured low quiescent current (<55uA typ.), low dropout voltage, and high output voltage accuracy. Built-in low on-resistance transistor provides low dropout voltage and large output current. A 2.2μF or greater can be used as an output capacitor.

The SOT-23-3 miniaturized package are recommended for configuring portable devices and large current application, respectively.

These robust devices are designed to prevent device failure under the worst operation condition with both Thermal Shutdown and Current Fold-back.

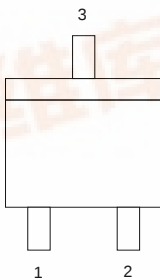
FEATURES

- ◆ Very Low Dropout Voltage
- ◆ Low Current Consumption: Typ. <55uA
- ◆ Output Voltage: 1.5V, 2.5V, 3.0V, 3.3V
- ◆ High Accuracy Output Voltage: +/- 1.5%
- ◆ Guaranteed >200mA Output
- ◆ Input Range of 1.8V to 7.0V
- ◆ Thermal Shutdown
- ◆ High PSRR to 60dB
- ◆ Compact Package: SOT-23-3, SOT-89
- ◆ Factory Pre-set Output Voltages
- ◆ Short Circuit Current Fold-Back
- ◆ Low Temperature Coefficient

APPLICATIONS

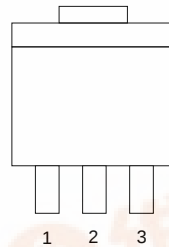
- ◆ Battery-powered devices, like DSC, MP3, portable DVD
- ◆ Personal communication devices
- ◆ Home electric/electronic appliances
- ◆ PC peripherals (PC card), Hard-disc

Pin define



SOT23-3

pin1 = GND ,
pin2 = Vout ,
Pin3 = Vin ,



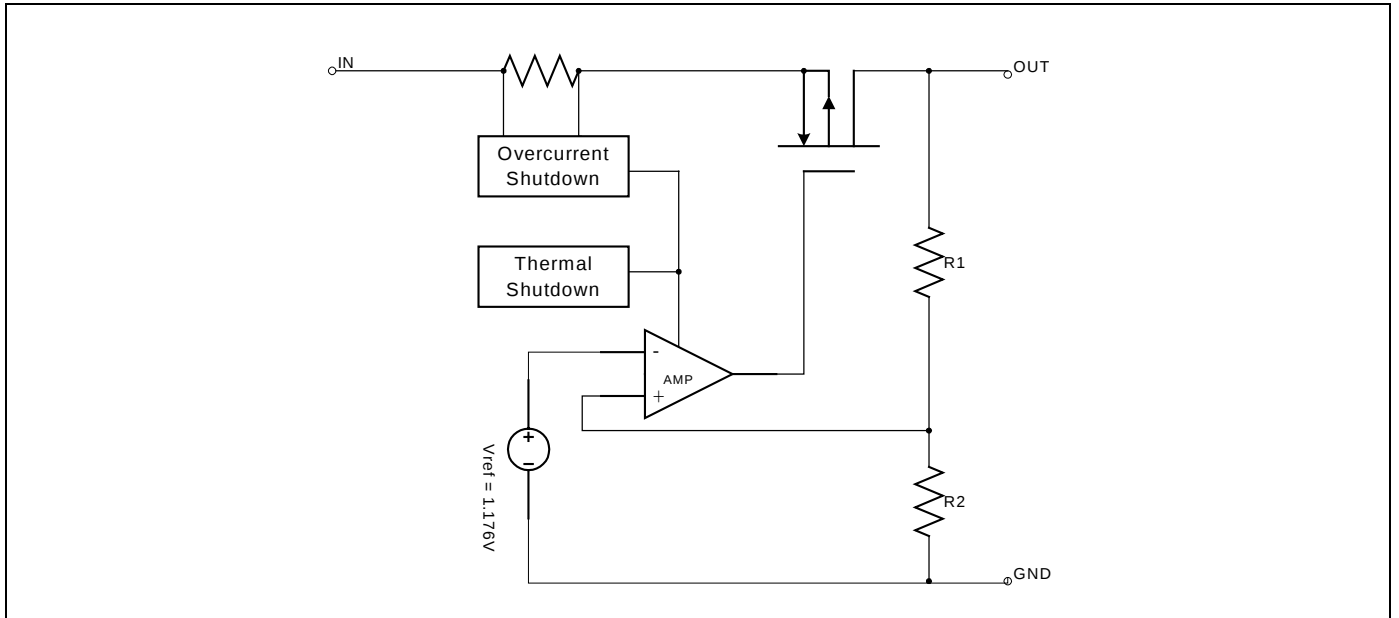
SOT89

pin1 = GND
pin2 = Vin
pin3 = Vout

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BLOCK DIAGRAM



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ORDERING INFORMATION

Part Number	Output Voltage	Temperature Range	Package
BM9166EIM23	1.5V	-40℃ ~ +85℃	SOT-23-3
BM9166EIM89	1.5V	-40℃ ~ +85℃	SOT-89
BM9166DIM23	1.8V	-40℃ ~ +85℃	SOT-23-3
BM9166DIM89	1.8V	-40℃ ~ +85℃	SOT-89
BM9166CIM23	2.5V	-40℃ ~ +85℃	SOT-23-3
BM9166CIM89	2.5V	-40℃ ~ +85℃	SOT-89
BM9166BIM23	2.8V	-40℃ ~ +85℃	SOT-23-3
BM9166BIM89	2.8V	-40℃ ~ +85℃	SOT-89
BM9166FIM23	3.0V	-40℃ ~ +85℃	SOT-23-3
BM9166FIM89	3.0V	-40℃ ~ +85℃	SOT-89
BM9166AIM23	3.3V	-40℃ ~ +85℃	SOT-23-3
BM9166AIM89	3.3V	-40℃ ~ +85℃	SOT-89

MARKING INFORMATION

Part Number	Output Voltage	Laser marking on chip	Package
BM9166EIM23	1.5V	66E (168E)	SOT-23-3
BM9166DIM23	1.8V	66D	SOT-23-3
BM9166CIM23	2.5V	66C	SOT-23-3
BM9166BIM23	2.8V	66B	SOT-23-3
BM9166FIM23	3.0V	66F	SOT-23-3
BM9166AIM23	3.3V	66A	SOT-23-3

Note: please contact Bookly Micro Sales office for detail if any concern or question on above information.

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ABSOLUTE MAXIMUM RATINGS

Input Voltage +7V
Output Current $P_D / (V_{IN} - V_O)$
Output Voltage GND-0.3V to $V_{IN}+0.3V$
ESD Classification B

OPERATING RATINGS

Ambient Temperature Range (T_A) -40°C to +85°C
Junction Temperature Range -40°C to +125°C

THERMAL INFORMATION

Parameter		Maximum	Unit
Thermal Resistance (θ_{jc})	SOT-23-3	110	°C/W
	SOT-89	18	
Thermal Resistance (θ_{ja})	SOT-23-3	325	°C/W
	SOT-89	180	
Internal Power Dissipation (P_D) ($\Delta T = 100^\circ\text{C}$)	SOT-23-3	300	mW
	SOT-89	550	
	SOT-89	2750*	
Maximum Junction Temperature		150	°C
Maximum Lead Temperature (10 Sec)		300	°C

*With Junction sink capable of twice times of θ_{jc}

Caution: Stress above the listed absolute rating may cause permanent damage to the device.

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ELECTRICAL CHARACTERISTICS

$T_A = +25^{\circ}\text{C}$; unless otherwise noted

Parameter	Test Conditions	BM9166			Unit
		Min.	Typ.	Max.	
Input Voltage		Note 1		7	V
Output Voltage Accuracy	$I_o = 1\text{mA to } 250\text{mA}$	-1.5		1.5	%
Dropout Voltage	$I_o=100\text{mA}, V_{OUT}=V_{OUT}-2.0\%, V_{OUT}>2.5\text{V}$		150mV		mV
	$I_o=100\text{mA}, V_{OUT}=V_{OUT}-2.0\%, V_{OUT}\leq 2.0\text{V}$		210mV		mV
Output Current	$V_{OUT} > 1.2\text{V}$	150			mA
Short Circuit Current	$V_{OUT} < 1.05\text{V}$			300	mA
Current Limit	$V_{OUT}>1.2\text{V}$	300	450		mA
Quiescent Current	$V_{IN}=5\text{V}, \text{No Load}$			55	μA
Ground Pin Current	$I = 1\text{mA to } 250\text{mA}$			60	μA
Line Regulation	$I_{OUT}=5\text{mA}, V_{IN}=V_{OUT}+1 \text{ to } V_{OUT}+2, V_{OUT} \leq 3.0\text{V}$	-0.15	0.03	0.15	%
	$I_{OUT}=5\text{mA}, V_{IN}=V_{OUT}+1 \text{ to } V_{OUT}+2, V_{OUT} > 3.0\text{V}$	-0.3	0.06	0.3	
Load Regulation	$I_o=1\text{mA to } 250\text{mA}$		0.2	1	%
Power Supply Rejection	$I_o = 100\text{mA}$ $C_o=10\mu\text{F ceramic}$	$f=1\text{KHz}$	60		dB
		$f=10\text{KHz}$	60		
		$f=100\text{KHz}$	46		
Over Temperature Shutdown			150		$^{\circ}\text{C}$
Over Temperature Hysteresis			30		$^{\circ}\text{C}$
Output Noise	$F=10\text{Hz to } 100\text{kHz}, C_o=10\mu\text{F}, I_o = 10\text{mA}$		30		μVrms
Output Voltage Temp. Coeff.			25		$\text{ppm}/^{\circ}\text{C}$

Note 1. $V_{IN(MIN)} = V_{OUT} + 0.3\text{V}$

DETAILED DESCRIPTION

The BM9166 family of CMOS regulators contain a PMOS pass transistor, voltage reference, error amplifier, over-current protection, thermal shutdown, and short circuit protection.

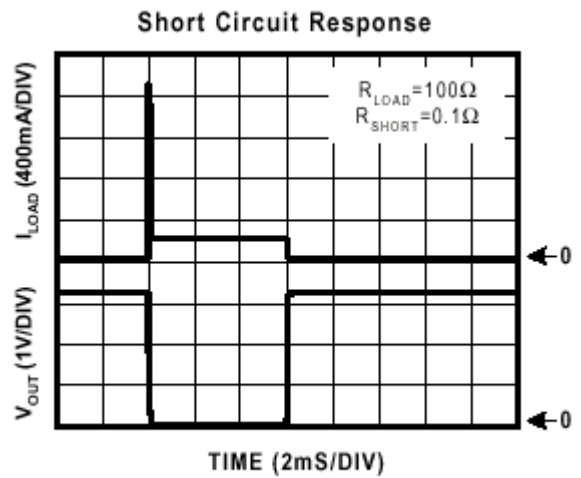
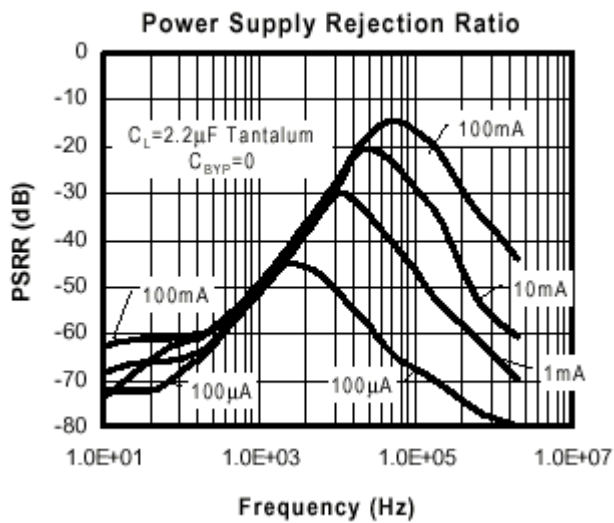
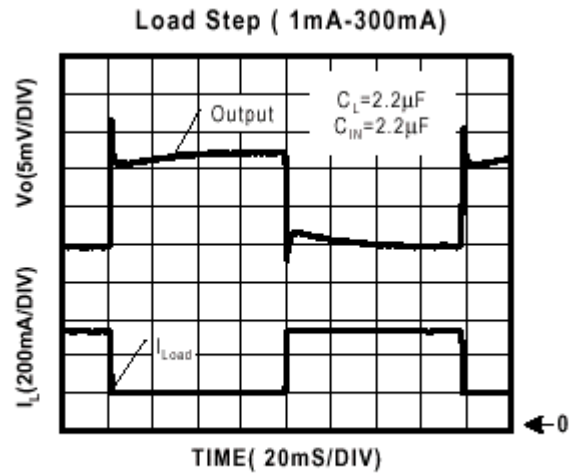
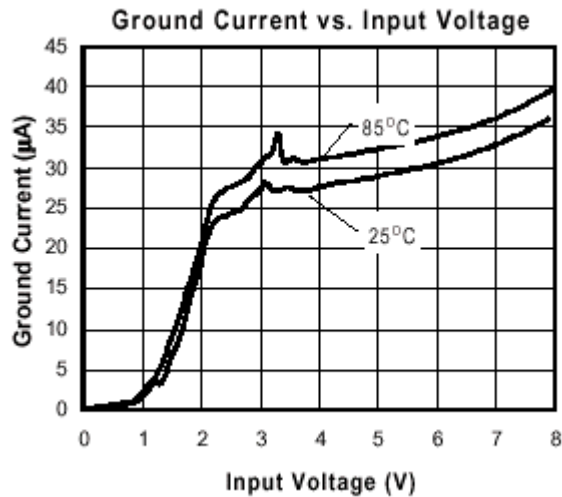
The P-channel pass transistor receives data from the error amplifier, over-current shutdown, short output protection, and thermal protection circuits. During normal operation, the error amplifier compares the output voltage to a precision reference. Over-current and Thermal shutdown circuits become active when the junction temperature exceeds 150°C , or the current exceeds 350mA . During thermal shutdown, the output voltage remains low. Normal operation is restored when the junction temperature drops below 120°C .

The BM9166 switches from voltage mode to current mode when the load exceeds the rated output current. This prevents over-stress. The BM9166 also incorporates current fold-back to reduce power dissipation when the output is short-circuited. This feature becomes active when the output drops below 1.05V , and reduces the current flow by 65%. Full current is restored when the voltage exceeds 1.05V .

EXTERNAL CAPACITOR

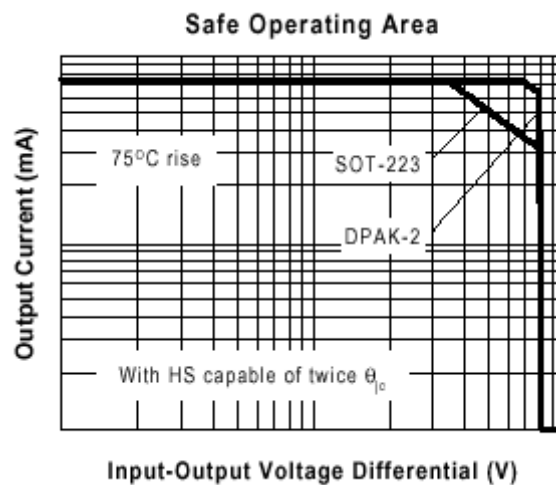
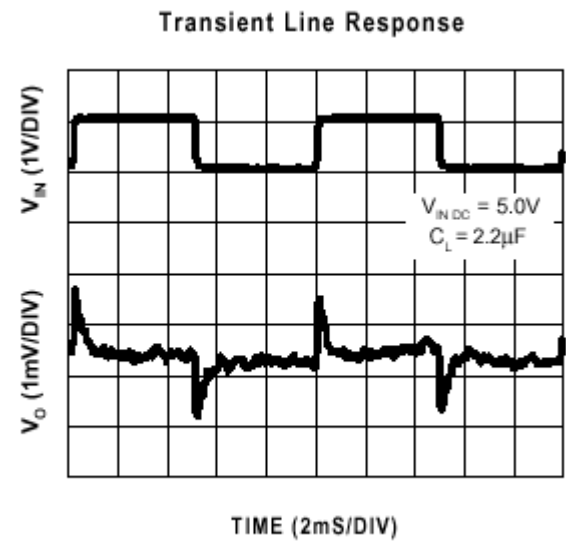
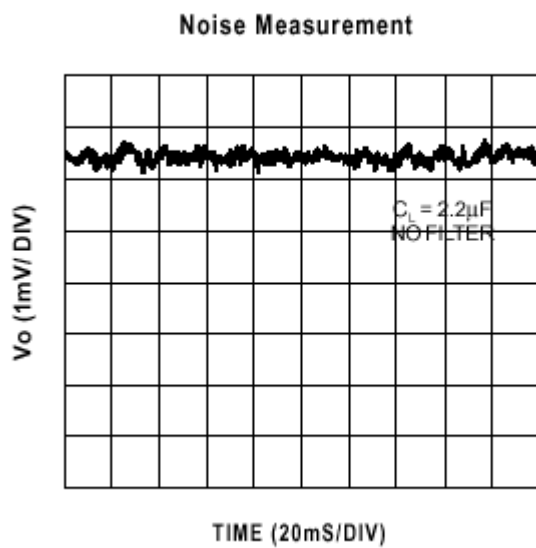
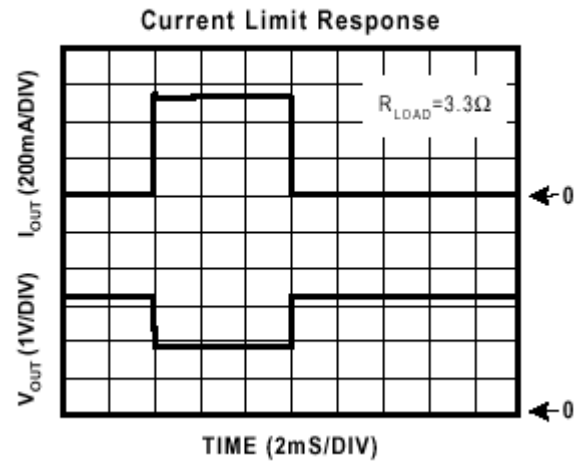
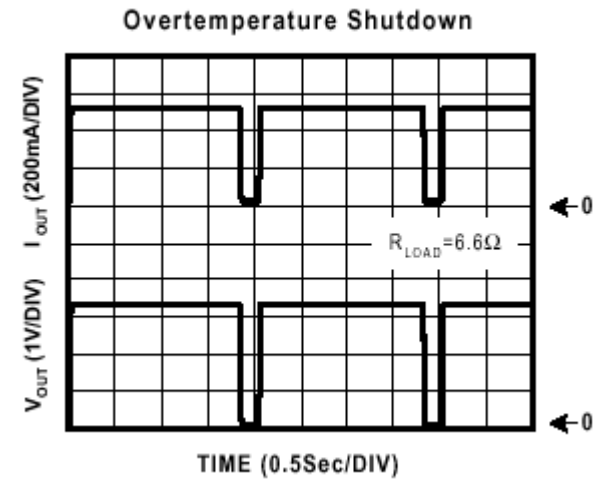
The BM9166 is stable with an output capacitor to ground of $2.2\mu\text{F}$ or $10\mu\text{F}$ is best. It can keep stable even with higher or poor ESR capacitors. A second capacitor is recommended between the input and ground to stabilize V_{IN} . The input capacitor should be larger than $0.1\mu\text{F}$ to have a beneficial effect. All capacitors should be placed in close proximity to the pins. A "quiet" ground termination is desirable.

TYPICAL ELECTRICAL CHARACTERISTICS



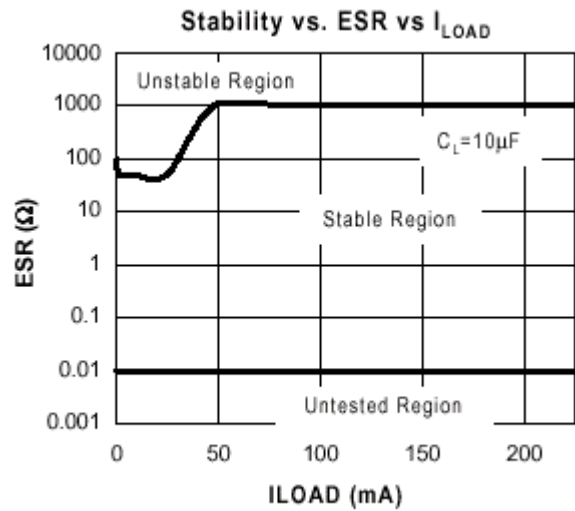
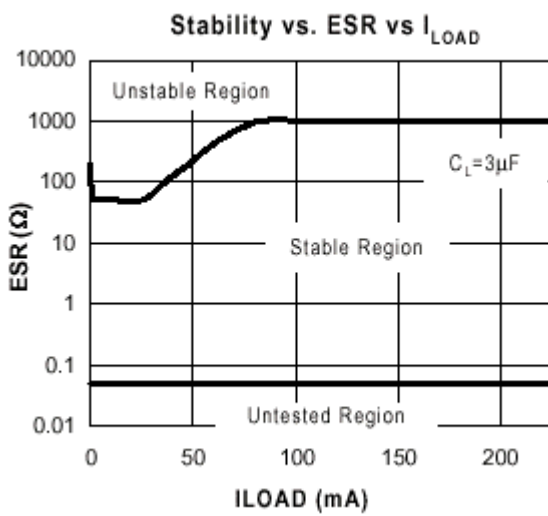
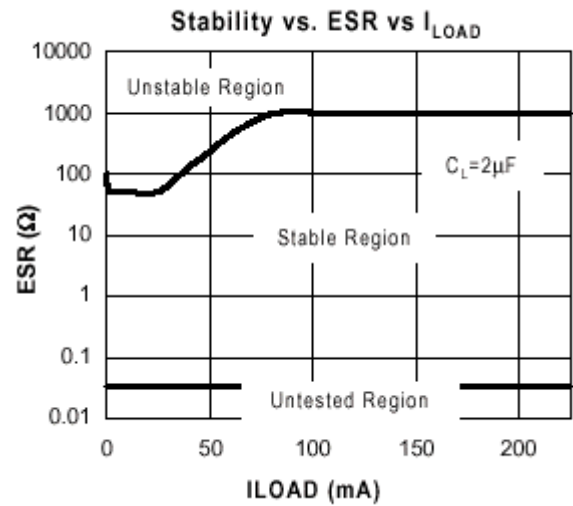
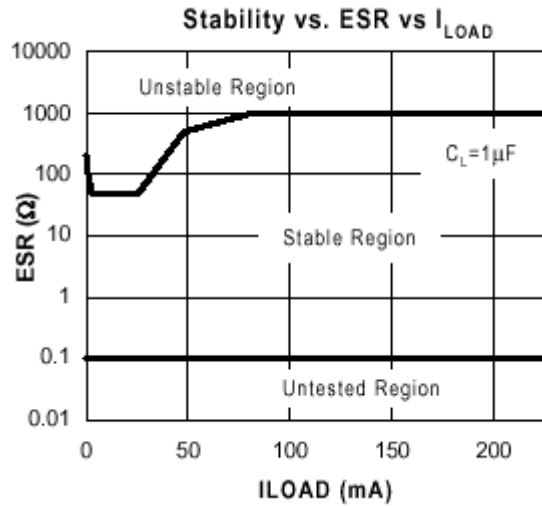
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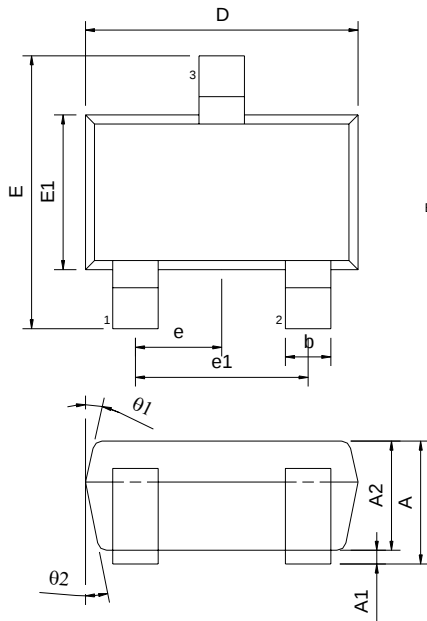


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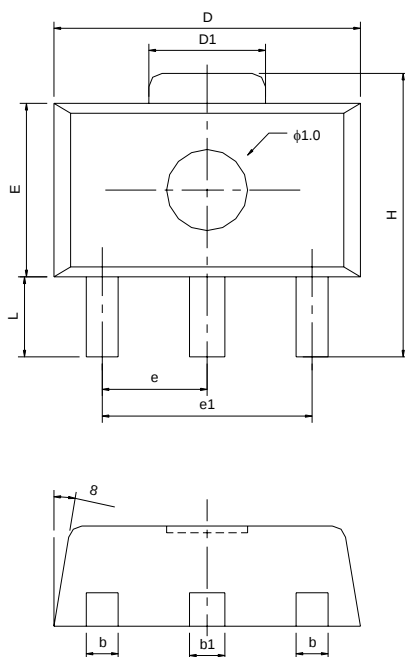
PACKAGE DIMENSION (CONTINUED)

SOT-23-3 (M23)



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.05	---	1.35	0.041	---	0.053
A1	0.05	---	0.15	0.002	---	0.006
A2	1.00	1.10	1.20	0.039	0.043	0.047
b	0.25	---	0.50	0.010	---	0.020
b1	0.25	0.40	0.45	0.010	0.016	0.018
c	0.08	---	0.20	0.003	---	0.008
c1	0.08	0.11	0.15	0.003	0.004	0.006
D	2.70	2.90	3.00	0.106	0.114	0.118
E	2.60	2.80	3.00	0.102	0.110	0.118
E1	1.50	1.60	1.70	0.059	0.063	0.067
L	0.35	0.45	0.55	0.014	0.018	0.022
L1	0.60 REF			0.024 REF		
e	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
θ	0°	5°	10°	0°	5°	10°
$\theta 1$	3°	5°	7°	3°	5°	7°
$\theta 2$	6°	8°	10°	6°	8°	10°

SOT-89 (M89)



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.40	1.50	1.60	0.055	0.059	0.063
L	0.80	---	1.20	0.031	---	0.047
b	0.36	0.42	0.48	0.014	0.016	0.018
b1	0.41	0.47	0.53	0.016	0.018	0.020
C	0.38	0.40	0.43	0.014	0.015	0.017
D	4.40	4.50	4.60	0.173	0.177	0.181
D1	1.40	1.60	1.75	0.055	0.062	0.069
H	3.94	---	4.25	0.155	---	0.167
E	2.40	2.50	2.60	0.094	0.098	0.102
e1	2.90	3.00	3.10	0.114	0.118	0.122
e	1.45	1.50	1.55	0.057	0.059	0.061